## Abstract Submitted for the MAR05 Meeting of The American Physical Society

Effects of He<sup>+</sup> ion irradiation on the two-band superconductivity of MgB<sub>2</sub> by point-contact spectroscopy WAN KYU PARK, BERND WILKEN, KAREN PARKINSON, LAURA GREENE, Department of Physics and Frederick Seitz Materials Research Laboratory, University of Illinois at Urbana-Champaign, Urbana, IL 61801, BRIAN MOECKLY, Superconductor Technologies Inc., Santa Barbara, CA 93111, JOHN ROWELL, Department of Chemical and Materials Engineering, Arizona State University, Tempe, AZ 85287 — An unresolved issue in MgB<sub>2</sub> is whether the two superconducting gaps can be merged into a single gap as  $T_c$  is reduced. It has been predicted that several effects, including enhanced interband scattering or a smeared density of states, can reduce  $T_c$ . Our transport measurements on MgB<sub>2</sub> thin films un-irradiated and irradiated with 1 MeV He<sup>+</sup> ions (doses:  $1 \times 10^{15} - 1 \times 10^{17} \text{ ions/cm}^2$ ) show that  $\rho_{40K}$  increases and that T<sub>c</sub> decreases roughly linearly with dose and  $\rho_{40K}$ , similar to other work [R. Gandikota et al., cont-mat/0410655]. Point-contact spectroscopy on MgB<sub>2</sub> irradiated with  $1 \times 10^{16}$ ions/cm<sup>2</sup>, with  $T_c$  reduced to 36.3 K from 39.3 K, shows that  $2\Delta/k_BT_c$  increases from 1.43 to 1.76 (decreases from 4.13 to 3.90) for the smaller (larger) gap, so the gaps tend to merge. Detailed measurements and analyses based on the existing models [e.q., J. M. Rowell, SST **16** R17 (2003), and J. Kortus et al., cond-mat/0411667 will be presented. We acknowledge Pavel Krasnochtchekov and Robert Averback and support by the DoE DEFG02-91ER45439, through the FSMRL and the Center for Microanalysis of Materials.

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